

# General purpose transistor (50V, 0.15A)

## 2SC2412K / 2SC4081 / 2SC4617 / 2SC5658 / 2SC1740S

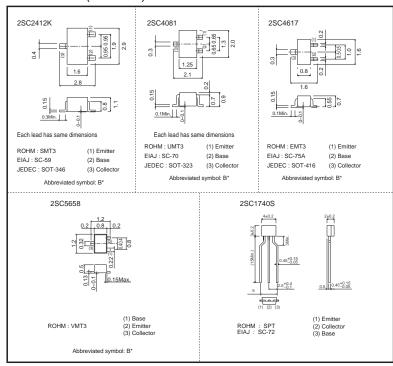
## Features

- 1. Low Cob. Cob=2.0pF (Typ.)Cob=2.0pF (Typ.)
- 2. Complements the 2SA1037AK / 2SA1576A / 2SA1774H / 2SA2029 / 2SA933AS.

## ●Structure

Epitaxial planar type NPN silicon transistor

## ●Dimensions (Unit:mm)



<sup>\*</sup> Denotes hre

## ●Absolute maximum (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	60	V	
Collector-emitter voltage		Vceo	50	V	
Emitter-base voltage		VEBO	7	V	
Collector current		lc	0.15	А	
Collector power dissipation	2SC2412K, 2SC4081		0.2		
	2SC4617, 2SC5658	Pc	0.15	W	
	2SC1740S		0.3		
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	°C	

## $\bullet \textbf{Electrical characteristics} \; (Ta = 25^{\circ}C) \\$

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	60	_	_	V	Ic=50μA
Collector-emitter breakdown voltage	BVceo	50	_	_	V	Ic=1mA
Emitter-base breakdown voltage	ВVево	7	_	-	V	Iε=50μA
Collector cutoff current	Ісво	-	_	0.1	μΑ	Vcb=60V
Emitter cutoff current	ІЕВО	-	_	0.1	μΑ	Veb=7V
DC current transfer ratio	hfe	120	_	390	_	Vce=6V, Ic=1mA
Collector-emitter saturation voltage	VcE(sat)	-	_	0.4	V	Ic/Iв=50mA/5mA
Transition frequency	f⊤	-	180	-	MHz	Vce=12V, Ie=-2mA, f=100MHz
Output capacitance	Cob	_	2	3.5	pF	Vce=12V, Ie=0A, f=1MHz

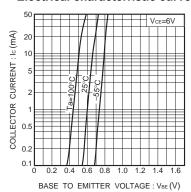
## ●Packaging specifications and hFE

		Package	Taping				
		Code	T146	T106	TL	T2L	TP
Туре	hfe	Basic ordering unit (pieces)	3000	3000	3000	8000	5000
2SC2412K	QR		0	_	_	_	_
2SC4081	QR		_	0	-	_	_
2SC4617	QR		_	_	0	_	_
2SC5658	QR		_	_	_	0	_
2SC1740S	QR		_	_	_	_	0

#### hfe values are classified as follows:

Item	Q	R		
hfE	120 to 270	180 to 390		

## •Electrical characterristic curves



Grounded emitter propagation characteristics

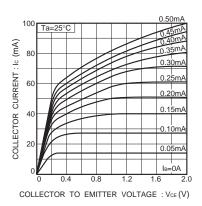


Fig.2 Grounded emitter output characteristics (I)

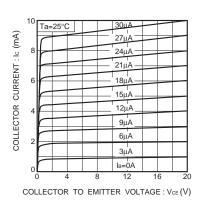


Fig.3 Grounded emitter output characteristics ( II )

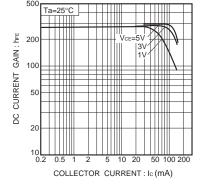


Fig.4 DC current gain vs. collector current (I)

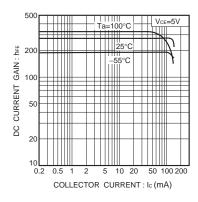


Fig.5 DC current gain vs. collector current ( II )

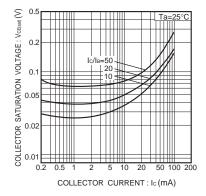


Fig. 6 Collector-emitter saturation voltage vs. collector current

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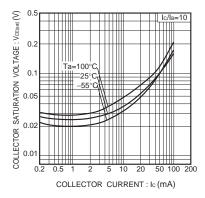


Fig.7 Collector-emitter saturation voltage vs. collector current ( I )

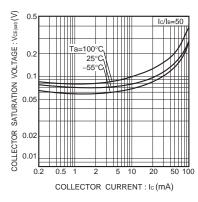


Fig.8 Collector-emitter saturation voltage vs. collector current (II)

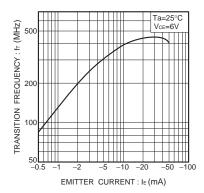


Fig.9 Gain bandwidth product vs. emitter current

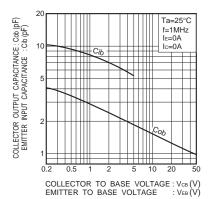


Fig.10 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

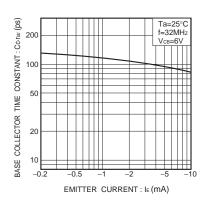


Fig.11 Base-collector time constant vs. emitter current

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